

# HCF4093

### Quad 2-input NAND Schmitt trigger

#### Datasheet - production data



### Features

- Schmitt trigger action on each input with no external components
- Hysteresis voltage typically 0.9 V at V<sub>DD</sub> = 5 V and 2.3 V at V<sub>DD</sub> =10 V
- Noise immunity greater than 50 % of V<sub>DD</sub> (typ.)
- No limit on input rise and fall times
- Quiescent current specified up to 20 V
- Standardized symmetrical output characteristics
- 5 V, 10 V, and 15 V parametric ratings
- Input leakage current I<sub>I</sub> = 100 nA (max.) at  $V_{DD}$  = 18 V and T<sub>A</sub> = 25 °C
- 100 % tested for quiescent current

- ESD performance
  - HBM: 2 kV
  - MM: 200 V
  - CDM: 1 kV

### Applications

- Automotive
- Industrial
- Computer
- Consumer

### Description

The HCF4093 is a monolithic integrated circuit fabricated in metal oxide semiconductor technology available in the SO14 package.

The HCF4093 consists of four Schmitt trigger circuits. Each circuit function has a 2-input NAND gate with Schmitt trigger action on both inputs. The gate switches at different points for positive and negative going signals. The difference between the positive voltage ( $V_P$ ) and the negative voltage ( $V_N$ ) is defined as hysteresis voltage ( $V_H$ ).

Order code	Temperature range	Package	Packing	Marking						
HCF4093M013TR	-55 ° C to +125 ° C	SO14		HCF4093						
HCF4093YM013TR (1)	-40 ° C to +125 ° C	SO14 (automotive grade) <sup>(1)</sup>	Tape and reel	HCF4093Y						

#### Table 1. Device summary table

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent.

# Contents

1	Pin information
2	Functional description4
3	Electrical characteristics5
4	Package information
	4.1 SO14 package information 10
5	Ordering information
6	Revision history



# 1 Pin information



### Table 2. Pin description

Pin no	Symbol	Name and function		
1, 2, 5, 6, 8, 9, 12, 13	A, B, C, D, E, F, G, H	Data inputs		
3, 4, 10, 11	J, K, L, M	Data outputs		
7	V <sub>SS</sub>	Negative supply voltage		
14	V <sub>DD</sub>	Positive supply voltage		



# 2 Functional description

Table 3. Truth table									
Ir	Inputs								
A, C, E, G	B, D, F, H	J, K, L, M							
L	L	Н							
L	н	Н							
Н	L	Н							
Н	Н	L							





-55 to 125

°C

#### **Electrical characteristics** 3

Top

Stressing the device above the ratings listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Supply voltage	-0.5 to +22	V
VI	DC input voltage	-0.5 to V <sub>DD</sub> + 0.5	V
l	DC input current	±10	mA
р	Power dissipation per package	200	mW
P <sub>D</sub>	Power dissipation per output transistor	100	11100
T <sub>op</sub>	Operating temperature	-55 to +125	°C
T <sub>stg</sub>	Storage temperature	-65 to +150	

#### Table 4. Absolute maximum ratings (AMR)

	1 5		
Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Supply voltage	3 to 20	V
VI	Input voltage	0 to V <sub>DD</sub>	v

Operating temperature

#### Table 5. Recommended operating conditions



### **Electrical characteristics**

			Test c	ondition	5. DC sp				Value						
_													-		
Sym.	Parameter	V <sub>I</sub> (V)	V <sub>O</sub> (V)	<b>Ι<sub>Ο</sub>  (μΑ)</b>	V <sub>DD</sub> (V)	TA	_ = 25 °	C	-40 to	85 °C	-55 to	125 °C	Unit		
		-1.(-)	-0(-)		- 00(-7	Min.	Тур.	Max.	Min.	Max.	Min.	Max.			
		0/5			5			1		30		30			
I.	Quiescent	0/10			10		0.02	2		60		60	μA		
۱L	current	0/15			15			4		120		120	μΛ		
		0/20			20		0.04	20		600		600			
	High level	0/5			5	4.95			4.95		4.95				
$V_{OH}$	output	0/10		<1	10	9.95			9.95		9.95				
	voltage	0/15			15	14.95			14.95		14.95				
	Low level	5/0			5										
$V_{OL}$	output	10/0		<1	10		0.05			0.05		0.05			
	voltage	15/0			15								_		
	Positive						5	2.2	2.9	3.6	2.2	3.6	2.2	3.6	
		а			10	4.6	5.9	7.1	4.6	7.1	4.6	7.1			
Vp	trigger				15	6.8	8.8	10.8	6.8	10.8	6.8	10.8			
۰P	threshold voltage				5	2.6	3.3	4.0	2.6	4	2.6	4			
	vollage	b			10	5.6	7	8.2	5.6	8.2	5.6	8.2			
					15	6.3	9.4	12.7	6.3	12.7	6.3	12.7	v		
	Negativo				5	0.9	1.9	2.8	0.9	2.8	0.9	2.8	, v		
		Negative	Negative	а			10	2.5	3.9	5.2	2.5	5.2	2.5	5.2	
V <sub>N</sub>	trigger				15	4	5.8	7.4	4	7.4	4	7.4			
۷N	threshold voltage				5	1.4	2.3	3.2	1.4	3.2	1.4	3.2			
	voltage	b			10	3.4	5.1	6.6	3.4	6.6	3.4	6.6			
					15	4.8	7.3	9.6	4.8	9.6	4.8	9.6			
					5	0.3	0.9	1.6	0.3	1.6	0.3	1.6			
		а			10	1.2	2.3	3.4	1.2	3.4	1.2	3.4			
V <sub>H</sub>	Hysteresis				15	1.6	3.5	5	1.6	5	1.6	5			
۷H	voltage				5	0.3	0.9	1.6	0.3	1.6	0.3	1.6			
		b			10	1.2	2.3	3.4	1.2	3.4	1.2	3.4			
					15	1.6	3.5	5	1.6	5	1.6	5			
_		0/5	2.5		5	-1.36	-3.2		-1.15		-1.1				
I <sub>ОН</sub>	Output drive	0/0	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA		
ЧUН	current	0/10	9.5		10	-1.1	-2.6		-0.9		-0.9				
		0/15	13.5		15	-3.0	-6.8		-2.4		-2.4				

Table 6. DC specifications<sup>(1)</sup>



	Table 6. DC specifications (continueu)												
		Test condition				Value							
Sym.	Parameter				N 00	Τ <sub>4</sub>	<b>= 25</b> °	С	-40 to	85 °C	-55 to	125 °C	Unit
				$\mathbf{V}_{\mathbf{I}}(\mathbf{V}) = \mathbf{V}_{\mathbf{O}}(\mathbf{V}) +  \mathbf{I}_{\mathbf{O}} (\mathbf{\mu}\mathbf{A}) + \mathbf{V}_{\mathbf{DD}}(\mathbf{V})$	V <sub>DD</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		0/5	0.4		5	0.44	1		0.36		0.36		
I <sub>OL</sub>	Output sink current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mA
		0/15	1.5		15	3.0	6.8		2.4		2.4		
I	Input leakage current	0/18	Any input		18		±10 <sup>-5</sup>	±0.1		±1		±1	μA
CI	Input capacitance		Any	input			5	7.5					pF

Table 6. DC specifications<sup>(1)</sup> (continued)

1. The noise margin for both level "1" and "0" is: 1 V min. with  $V_{DD}$  = 5 V, 2 V min. with  $V_{DD}$  = 10 V, and 2.5 V min. with  $V_{DD}$  = 15 V. a: Input on terminals 1, 5, 8, 12 or 2, 6, 9, 13; other inputs to  $V_{DD}$ .

b: Input on terminals 1 and 2, 5 and 6, 8 and 9, or 12 and 13; other inputs to  $V_{\mbox{\scriptsize DD}}.$ 

$(I_{amb} = 25 °C, C_L = 50 pF, R_L = 200 K\Omega, t_r = t_f = 20 ns)$								
Symbol	Parameter	Test condition	Valu	Unit				
	Falameter	V <sub>DD</sub> (V)	Тур.	Max.	onit			
		5	190	380				
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation delay time	10	90	180				
		15	65	130	ne			
		5	100	200	ns			
t <sub>TLH</sub> , t <sub>THL</sub>	Output transition time	10	50	100				
		15	40	80				

 
 Table 7. Dynamic electrical characteristics
 $= 25 \,^{\circ}\text{C}$  C = 50 pE R = 200 kO t = t = 20 ps) **/T** 

1. The typical temperature coefficient for all  $V_{DD}$  values is 0.3 %/°C.





1. Legend: C<sub>L</sub> = 50 pF or equivalent (includes jig and probe capacitance), R<sub>L</sub> = 200 K $\Omega$ , R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50  $\Omega$ )



Figure 4. Propagation delay time waveform (f = 1 MHz; 50 % duty cycle)



## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



### 4.1 SO14 package information



### Figure 5. SO14 package mechanical drawing

#### Table 8. SO14 package mechanical data

		Dimensions									
Ref		Millimeters		Inches							
	Min.	Тур.	Max.	Min.	Тур.	Max.					
А			1.75			0.068					
a1	0.1		0.2	0.003		0.007					
a2			1.65			0.064					
b	0.35		0.46	0.013		0.018					
b1	0.19		0.25	0.007		0.010					
С		0.5			0.019						
c1		45 °			45 °						
D	8.55		8.75	0.336		0.344					
E	5.8		6.2	0.228		0.244					
е		1.27			0.050						
e3		7.62			0.300						
F	3.8		4.0	0.149		0.157					
G	4.6		5.3	0.181		0.208					
L	0.5		1.27	0.019		0.050					
М			0.68			0.026					
S			8 °			8 °					





1. Drawing is not to scale.

	Dimensions										
Ref		Millimeters			Inches						
	Min.	Тур.	Max.	Min.	Тур.	Max.					
А			330			12.992					
С	12.8		13.2	0.504		0.519					
D	20.2			0.795							
Ν	60			2.362							
Т			22.4			0.882					
Ao	6.4		6.6	0.252		0.260					
Во	9		9.2	0.354		0.362					
Ko	2.1		2.3	0.082		0.090					
Po	3.9		4.1	0.153		0.161					
Р	7.9		8.1	0.311		0.319					

Table 9. SO14 tape and reel information



## 5 Ordering information

#### Table 10. Order codes

Order code	Temperature range	Package	Packing	Marking
HCF4093M013TR	-55 ° C to +125 ° C	SO14	Tape and	HCF4093
HCF4093YM013TR (1)	-40 ° C to +125 ° C	SO14 (automotive grade) <sup>(1)</sup>	reel	HCF4093Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q002 or equivalent.

### 6 Revision history

Date	Revision	Changes
Sept-2001	1	Initial release.
16-Aug-2007	2	Document converted to new ST template, added <i>Figure 6: SO14</i> tape and reel information on page 11 and Table 9: SO14 tape and reel information on page 11, small text changes.
18-Feb-2013	3	Document template and layout updated Updated package names (PDIP-14 and SO-14 instead of DIP-14 and SOP-14). Updated <i>Features</i> Added <i>Applications</i> Updated <i>Device summary table</i> Small correction to inches min value of Ao in <i>Table 9</i> Added <i>Section 5: Ordering information</i>
13-Jan-2014	4	Removed PDIP14 package Added ESD data to <i>Features</i> <i>Table 1: Device summary table</i> : updated footnote <i>1.</i> <i>Table 10: Order codes</i> : updated footnote <i>1.</i>

#### Table 11. Document revision history



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